

### Integrated EMI Filter & ESD Protection for **Earpiece Speaker & Microphone Ports**

**PRODUCTION DATA SHEET** 

### DESCRIPTION

Proliferation of digital portable electronic equipment has created a filter with ESD protection that filters noisy environment in which all out the undesired frequencies as well as become susceptible devices Electromagnetic Interference (EMI). and negative ESD voltages. The device Interference form cell frequencies of 800-900 MHz and 1.5 x 1.0 x 0.65 mm. The small size 1.9GHz as well as the growing and profile of this device is ideally wireless LAN frequencies of 2.4- suited for portable applications. The 6GHz can couple into the audio port absence of leadframe and bondwires of a handheld device and adversely minimizes inductance and optimizes the affect its performance. FCC Part 15 high frequency filter performance. sets maximum allowable emission and LX7206 exceeds the requirements of immunity levels for all digital devices. IEC61000-4-2 (15KV air discharge and

LX7206 is an integrated low pass to protecting the port against both positive phone is a 3x2 array flip chip and measures 8KV contact discharge).

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

#### BENEFITS

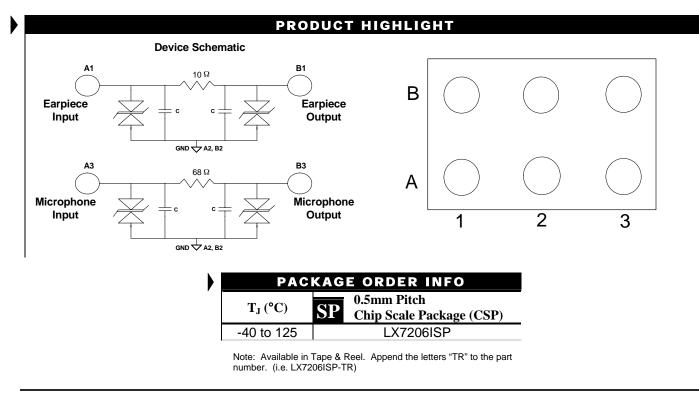
- Filter response characterized up to 6 GHz
- Low insertion loss in the pass band
- >20dB attenuation in the 800-900 MHz range
- >15dB attenuation in the WLAN frequencies of 2.4GHz and 5.0-6.0 GHz

### **KEY FEATURES**

- Flip Chip construction
- Bi-directional EMI/RFI low-pass filter
- ESD protection with integrated line termination resistor
- **Bi-directional TVS protects** against negative ESD voltages in audio applications
- Low TVS operating voltage (5.0V)
- Low leakage current
- 0.5mm Pitch Chip Scale Package designed for direct assembly on FR4 PCB using conventional assembly techniques

#### APPLICATIONS

- Cell phones and Accessories
- Personal Digital Assistants (PDA's)
- Pagers
- MP3 Players
- Desktops and Notebook Computers
- **Digital Camcorders**





## Integrated EMI Filter & ESD Protection for Earpiece Speaker & Microphone Ports

**PRODUCTION DATA SHEET** 

### ABSOLUTE MAXIMUM RATINGS

Peak Pulse Power (tp = $8/20 \ \mu s$ ) IEC61000-4-5	
Peak Pulse Current (tp = $8/20 \ \mu s$ ) IEC61000-4-5	26A
ESD Air Discharge per IEC61000-4-2	
ESD Contact Discharge per IEC61000-4-2	
Operating Temperature	40°C to +125°C
Storage Temperature Range	55°C to +150°C

Note: Exceeding these ratings could cause damage to the device. All voltages are with respect to Ground. Currents are positive into, negative out of specified terminal.



PACKAGE PIN OUT

SP PACKAGE (Top View)

FUNCTIONAL PIN DESCRIPTION							
Name	Description						
A1	Line 1 input						
B1	Line 1 output						
A2 & B2	Ground						
A3	Line 2 input						
B3	Line 2 output						
B3	Line 2 output						

) y

### **ELECTRICAL CHARACTERISTICS**

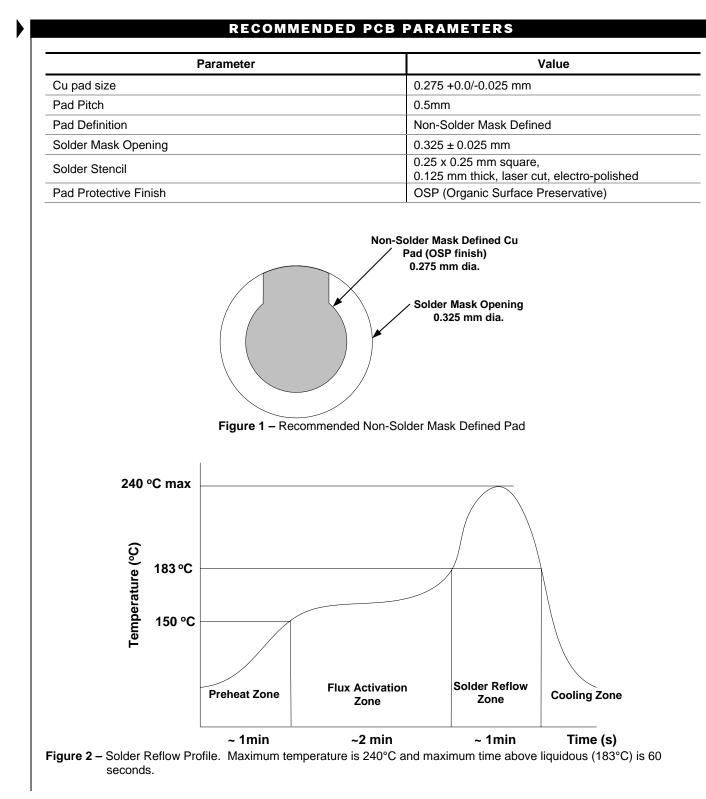
Unless otherwise specified, the following specifications apply over the operating ambient temperature  $0^{\circ}C \le T_A \le 70^{\circ}C$  except where otherwise noted.

Parameter	Symbol	Test Conditions		LX7206						
Falailletei			Min	Тур	Max	Units				
SECTION HEADER										
Stand-Off Voltage	V <sub>RWM</sub>				5.0	V				
Breakdown Voltage	V <sub>BR</sub>	I <sub>R</sub> = 1mA	6			V				
Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = + -5.0V, T = 25°C	-1		1	μA				
Series Resistance, A1 to B1	Rs		9	10	11	Ω				
Series Resistance, A3 to B3	Rs		61	68	75	Ω				
Temperature Coefficient of R <sub>S</sub>	T <sub>COEFF</sub>	Each Line		200		ppm				
Capacitor, A1 or B1 to GND	С	V <sub>R</sub> = 2.5V, f = 1 MHz	115	145	175	pF				
Capacitor, A3 or B3 to GND	С	V <sub>R</sub> = 2.5V, f = 1 MHz	115	145	175	pF				



Integrated EMI Filter & ESD Protection for Earpiece Speaker & Microphone Ports

**PRODUCTION DATA SHEET** 

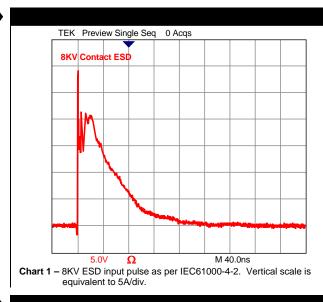


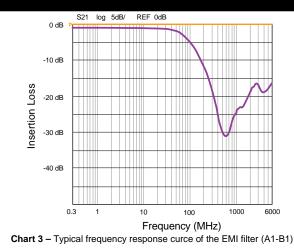
Copyright © 2004 Rev. 1.0, 2004-10-05



## Integrated EMI Filter & ESD Protection for Earpiece Speaker & Microphone Ports

**PRODUCTION DATA SHEET** 





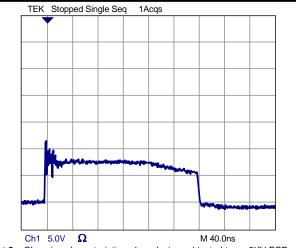
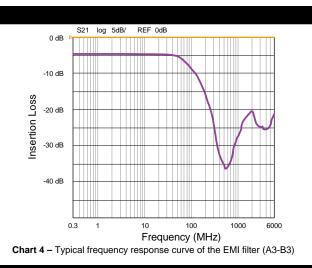


Chart 2 - Clamping characteristics when device subjected to an 8KV ESD pulse.



14 12 Clamping Voltage VC(V) 10 8 6 Line To GND 4 GND to Line 2 0 0 5 15 20 25 10 30 Peak Pulse Current IPP(A)

 $\textbf{Chart 5} - Clamping \ voltage \ versus \ Peak \ Pulse \ Current. \ Waveform \ parameters: t_r = 8\mu s, t_d = 20\mu s. \ Per \ IEC61000-4-5$ 

Copyright © 2004 Rev. 1.0, 2004-10-05

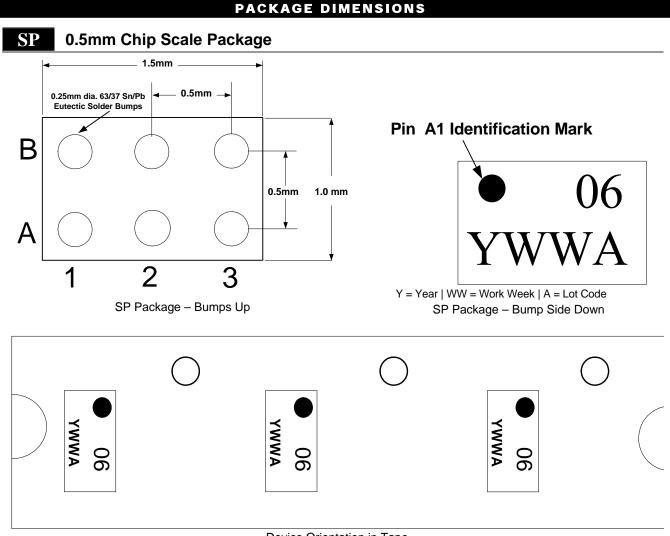
#### *Microsemi* Integrated Products Division 11861 Western Avenue, Garden Grove, CA. 92841, 714-898-8121, Fax: 714-893-2570

www.*Microsemi.*com



Integrated EMI Filter & ESD Protection for Earpiece Speaker & Microphone Ports

**PRODUCTION DATA SHEET** 



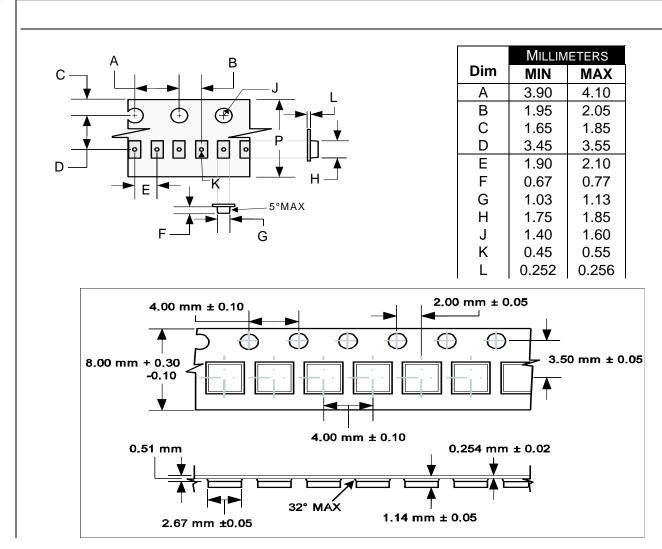
Device Orientation in Tape



Integrated EMI Filter & ESD Protection for Earpiece Speaker & Microphone Ports

**PRODUCTION DATA SHEET** 

## TAPE SPECIFICATIONS





Integrated EMI Filter & ESD Protection for Earpiece Speaker & Microphone Ports

**PRODUCTION DATA SHEET** 

NOTES

NOTES

PRODUCTION DATA – Information contained in this document is proprietary to Microsemi and is current as of publication date. This document may not be modified in any way without the express written consent of Microsemi. Product processing does not necessarily include testing of all parameters. Microsemi reserves the right to change the configuration and performance of the product and to discontinue product at any time.